



MDL-III-808L/1~100mW



INFRARED DIODE LASER
AT 808nm

It features ultra compact design, long lifetime, cost-effectiveness and easy operation. They are used in measurement, communication, spectrum analysis, etc.



SPECIFICATIONS

Central wavelength (nm)	808±10
Operating mode	CW
Output power (mW)	>1, 10, 20,..., 100
Power stability (rms, over 4 hours)	<3%, <2%, <1%, <0.5%
Transverse mode	Near TEM ₀₀
M ² factor	~1.5 (~1.2, optional)
Beam diameter at the aperture ((1/e ² ,mm)	~3.5 (~1.2, optional)
Beam divergence, full angle (mrad)	<1.0
Polarization ratio	>50:1 (>100:1, optional) Horizontal±5 degree (Vertical Optional)
Warm-up time (minutes)	<5
Pointing stability after warm-up (mrad)	<0.05
Beam height from base plate (mm)	24.8
Operating temperature (°C)	10~35
Power supply	85-264VAC
	100-240VAC
Modulation optional	PSU-III-LED/ PSU-III-FDA (Frequency for 1Hz-30kHz) PSU-A-D (Frequency for 30kHz -100kHz)
Expected lifetime (hours)	TTL on/off, 1Hz-1kHz, 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz; and Analog modulation optional
Warranty	10000
	1 year



MDL-III-808L	PSU-III-LED	PSU-III-FDA	PSU-A-D
<p>143.5(L)×73(W)×46.2(H) mm³, 0.7kg</p>	<p>188.6 (L) ×155(W) ×92 (H) mm³, 1.5kg</p>	<p>171(L) ×130(W) ×62.2 (H) mm³, 1.2kg</p>	<p>162(L) ×144(W) ×70 (H) mm³, 1.0kg</p>